

General Purpose PNP Transistor

FEATURES

- Low $V_{CE(SAT)}$ -0.4 @ $I_C / I_B = -150 mA / -15 mA$
- PNP Silicon Transistor
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
BV_CBO		-60	V	
BV_CEO		-60	V	
I_{C}		-0.6	Α	
$V_{CE(SAT)}$	I _C =-150mA, I _B =-15mA	-0.4	V	



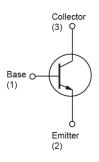




APPLICATION

- Consumer electronics
- General purpose amplification



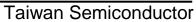


Notes: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	T UNIT	
Collector-Base Voltage	V_{CBO}	-60	V	
Collector-Emitter Voltage	V_{CEO}	-60	V	
Emitter-Base Voltage	V_{EBO}	-5	V	
Collector Current	I _C	-0.6	А	
Collector Power Dissipation	P _D	225	mW	
Operating Junction Temperature	TJ	+150	°C	
Operating Junction and Storage Temperature Range	T _{STG}	- 55 to +150	°C	

Note: Single pulse, $Pw \le 380\mu s$, $Duty \le 2\%$

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	556	°C/W	





ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 1)						
Collector-Base Breakdown Voltage	I_{C} =-10 μ A, I_{E} =0	BV _{CBO}	-60		-	٧
Collector-Emitter Breakdown Voltage	I _C =-10mA, I _B =0	BV _{CEO}	-60		-	٧
Emitter-Base Breakdown Voltage	I _E =-10μΑ, I _C =0	BV_{EBO}	-5			٧
Collector Cutoff Current	V _{CB} =-50V, I _E =0	I _{CBO}			-10	nA
Emitter Cutoff Current	V _{EB} =-0.5V, V _{CE} =-30V	I _{EBO}			-50	nA
Collector-Emitter Saturation Voltage	I _C /I _B =-150mA /-15mA	*V _{CE(SAT)}			-0.4	V
Base-Emitter Saturation Voltage	I _C /I _B =-500mA /-50mA	*V _{BE(SAT)}			-1.3	٧
DC Comment Transfer Datio	$V_{CE} = -10V, I_{C} = -0.1A$	*h _{FE} 1	75			
DC Current Transfer Ratio	$V_{CE} = -10V, I_{C} = -150mA$	*h _{FE} 2	100		300	
Transition Frequency	V_{CE} =-5V, I_{C} =-50mA, f=100MHz	f _T	200			MHz
Output Capacitance	V _{CB} = -10V, f=1MHz	Cob			8	pF

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Note: Pulse test: ≤ 380µs, duty cycle ≤ 2%

ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSA1036CX RFG	SOT-23	3,000pcs / 7" Reel



ELECTRICAL CHARACTERICS CURVES (T_A=25°C, unless otherwise noted)

Figure 1. DC Current Gain

1000
100
100
100
100
10
100
100
1c[mA], Collector Current

Figure 3. V_{BE(SAT)} v.s. Ic

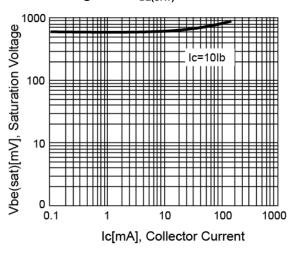


Figure 5. Power Derating Curve

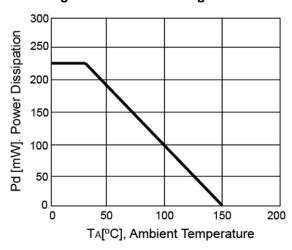


Figure 2. V_{CE(SAT)} v.s. lc

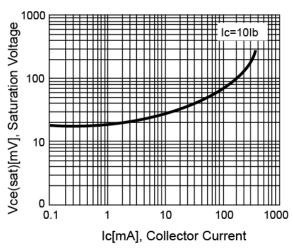
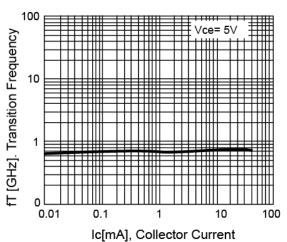


Figure 4. Cutoff Frequency vs. Ic



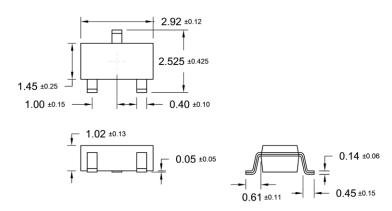
Version: C1906

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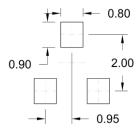


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

SOT-23



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



2T = Device Code

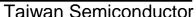
xx = Year Code + Month Code Year Code: 7=2017, 8=2018

Month Code:

 1 =Jan
 2 =Feb
 3 =Mar
 4 =Apr

 5 =May
 6 =Jun
 7 =Jul
 8 =Aug

 9 =Sep
 A =Oct
 B =Nov
 C =Dec





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